NSN 5962-01-110-7290

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-110-7290 **Body Length:** Between 1.235 inches and 1.285 inches **Body Width:** Between 0.515 inches and 0.600 inches **Body Height:** Between 0.145 inches and 0.187 inches **Maximum Power Dissipation Rating:** 0.09 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and monolithic and positive outputs and schottky and low power and 3-state output **Inclosure Material:** Ceramic and glass **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 13 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 5.5 volts power source **Time Rating Per Chacteristic:** 80.00 nanoseconds propagation delay time, low to high level output and 80.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Rom **Memory Capacity:** Unknown **Terminal Type And Quantity:** 24 printed circuit Shelf Life: N/a **Unit Of Measure:**

Demilitarization:

Yes - demil/mli

Fiig:

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